

# **HZS-L Series**

Silicon Planar Zener Diode for Low Noise Application

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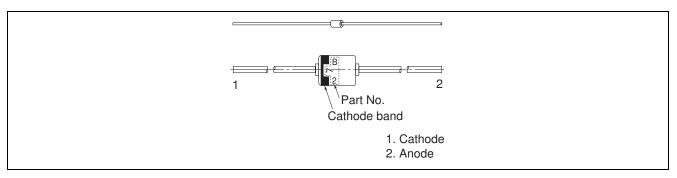
# Features

- Diode noise level of this series is approximately 1/3-1/10 lower than the HZ series.
- Low leakage, low zener impedance and maximum power dissipation of 400 mW are ideally suited for stabilized power supply, etc.
- Wide voltage range from 5.2 V through 38 V of zener voltage provide flexible application.
- Suitable for 5mm-pitch high speed automatic insertion.

# **Ordering Information**

Part No.	Cathode Band	Package Name	Package Code
HZS-L Series	Black	MHD	GRZZ0002ZC-A

# **Pin Arrangement**



# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Power dissipation	Pd	400	mW
Junction temperature	Тј	200	°C
Storage temperature	Tstg	–55 to +175	°C

# **Electrical Characteristics**

	Zener Voltage			Reverse Current		$(Ta = 25^{\circ}C)$ Dynamic Resistance	
	· · · · ·	zener voltage	Test	nevers	Test	Dynamic	Test
	V-7 (	V) * <sup>1</sup>	Condition	Ι <sub>R</sub> (μΑ)	Condition	r <sub>d</sub> (Ω)	Condition
Part No.	Min	Max	I <sub>z</sub> (mA)	Max	V <sub>R</sub> (V)	Max	I <sub>z</sub> (mA)
HZS6A1L	5.2	5.5	0.5	1	2.0	150	0.5
HZS6A2L	5.3	5.6					
HZS6A3L	5.4	5.7					
HZS6B1L	5.5	5.8	0.5	1	2.0	80	0.5
HZS6B2L	5.6	5.9					
HZS6B3L	5.7	6.0					
HZS6C1L	5.8	6.1	0.5	1	2.0	60	0.5
HZS6C2L	6.0	6.3					
HZS6C3L	6.1	6.4					
HZS7A1L	6.3	6.6	0.5	1	3.5	60	0.5
HZS7A2L	6.4	6.7					
HZS7A3L	6.6	6.9					
HZS7B1L	6.7	7.0					
HZS7B2L	6.9	7.2					
HZS7B3L	7.0	7.3					
HZS7C1L	7.2	7.6					
HZS7C2L	7.3	7.7					
HZS7C3L	7.5	7.9					
HZS9A1L	7.7	8.1	0.5	1	6.0	60	0.5
HZS9A2L	7.9	8.3					
HZS9A3L	8.1	8.5					
HZS9B1L	8.3	8.7					
HZS9B2L	8.5	8.9					
HZS9B3L	8.7	9.1					
HZS9C1L	8.9	9.3					
HZS9C2L	9.1	9.5					
HZS9C3L	9.3	9.7					
HZS11A1L	9.5	9.9	0.5	1	8.0	80	0.5
HZS11A2L	9.7	10.1					
HZS11A3L	9.9	10.3					
HZS11B1L	10.2	10.6					
HZS11B2L	10.4	10.8					
HZS11B3L	10.7	11.1					
HZS11C1L	10.9	11.3					
HZS11C2L	11.1	11.6					
HZS11C3L	11.4	11.9					

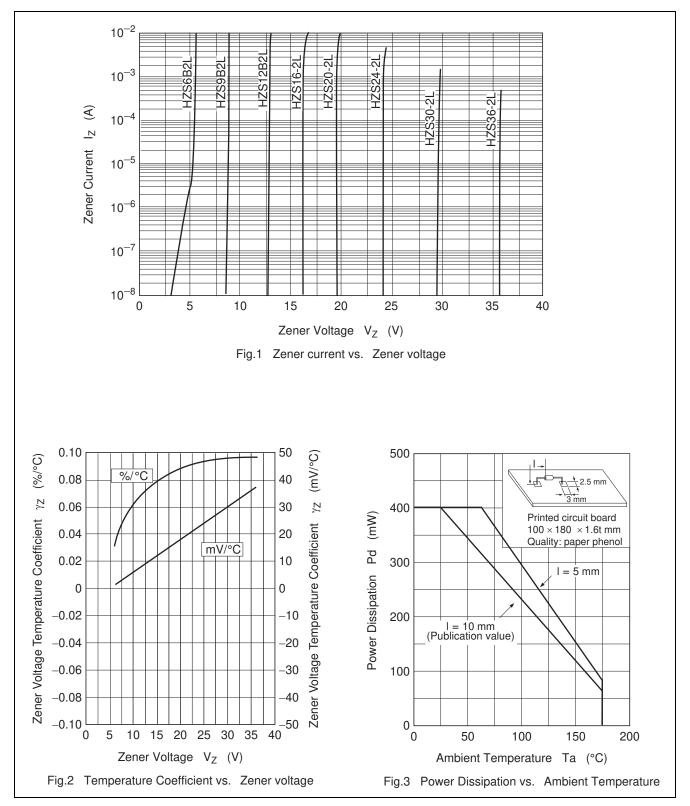
Note: 1. Tested with DC.

$(Ta = 25^{\circ}C)$	)	$^{\circ}C$	25°	=	(Ta	
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	Zener Voltage				Reverse Current		Dynamic Resistance	
			Test		Test		Test	
	V <sub>z</sub> (V		Condition	I <sub>R</sub> (μ <b>Α</b> )	Condition	r <sub>d</sub> (Ω)	Condition	
Part No.	Min	Мах	l <sub>z</sub> (mA)	Max	V <sub>R</sub> (V)	Max	I <sub>Z</sub> (mA)	
HZS12A1L	11.6	12.1	0.5	1	10.5	80	0.5	
HZS12A2L	11.9	12.4						
HZS12A3L	12.2	12.7						
HZS12B1L	12.4	12.9						
HZS12B2L	12.6	13.1						
HZS12B3L	12.9	13.4						
HZS12C1L	13.2	13.7						
HZS12C2L	13.5	14.0						
HZS12C3L	13.8	14.3						
HZS15-1L	14.1	14.7	0.5	1	13.0	80	0.5	
HZS15-2L	14.5	15.1						
HZS15-3L	14.9	15.5						
HZS16-1L	15.3	15.9	0.5	1	14.0	80	0.5	
HZS16-2L	15.7	16.5						
HZS16-3L	16.3	17.1						
HZS18-1L	16.9	17.7	0.5	1	15.0	80	0.5	
HZS18-2L	17.5	18.3	_					
HZS18-3L	18.1	19.0						
HZS20-1L	18.8	19.7	0.5	1	18.0	100	0.5	
HZS20-2L	19.5	20.4						
HZS20-3L	20.2	21.1						
HZS22-1L	20.9	21.9	0.5	1	20.0	100	0.5	
HZS22-2L	21.6	22.6	_					
HZS22-3L	22.3	23.3	_					
HZS24-1L	22.9	24.0	0.5	1	22.0	120	0.5	
HZS24-2L	23.6	24.7	_					
HZS24-3L	24.3	25.5	_					
HZS27-1L	25.2	26.6	0.5	1	24.0	150	0.5	
HZS27-2L	26.2	27.6						
HZS27-3L	27.2	28.6						
HZS30-1L	28.2	29.6	0.5	1	27.0	200	0.5	
HZS30-2L	29.2	30.6				_00	0.0	
HZS30-3L	30.2	31.6	_					
HZS33-1L	31.2	32.6	0.5	1	30.0	250	0.5	
HZS33-2L	32.2	33.6	- 0.0	•	00.0	200	0.0	
HZS33-3L	33.2	34.6	-					
HZS36-1L	34.2	34.0	0.5	1	33.0	300	0.5	
HZS36-2L	35.3	36.8	0.5	I	00.0	500	0.5	
HZS36-3L	36.4	38.0	-					

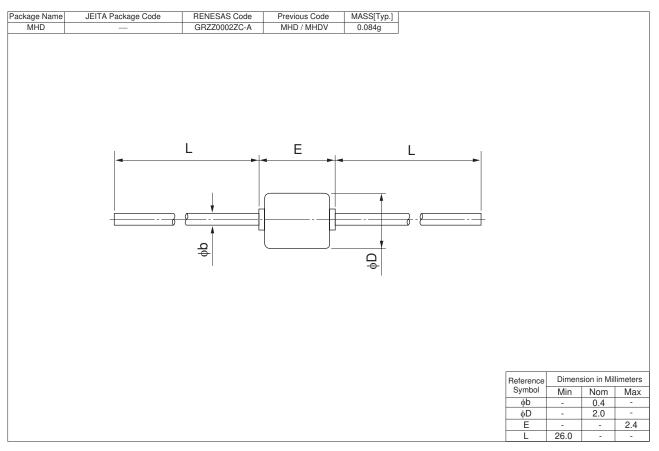
Note: 1. Tested with DC.

# **Main Characteristic**



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# **Package Dimensions**



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